NSN 5962-01-314-6450

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View Online at https://aerobasegroup.com/nsn/5962-01-314-6450

Body Length:
0.440 inches
Body Width:
0.285 inches
Body Height:
0.085 inches
Maximum Power Dissipation Rating:
794.0 milliwatts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Monolithic and schottky and bipolar
Inclosure Material:
Ceramic
Inclosure Configuration:
Flat pack
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
10 input
Case Outline Source And Designator:
F-5 mil-m-38510
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
7.0 volts power source
Time Rating Per Chacteristic:
35.00 nanoseconds propagation delay time, low to high level output and 35.00 nanoseconds propagation delay time, high to low level
output
Memory Device Type:
Rom
Test Data Document:
81349-mil-m-38510 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).
Terminal Type And Quantity:
16 flat leads
Specification Data:

Unit Of Measure:

Shelf Life:

N/a

81349-mil-m-38510/204 government specification

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Demilitarization:

Yes - demil/mli

Fiig:

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